







SGS TH07/1033

TH97/2478

TH09/2479

# **S1A ~ S1M**

**PRV**: 50 - 1000 Volts **Io**: 1.0 Ampere

#### **FEATURES:**

- \* High current capability
- \* High surge current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* Pb / RoHS Free

#### **MECHANICAL DATA:**

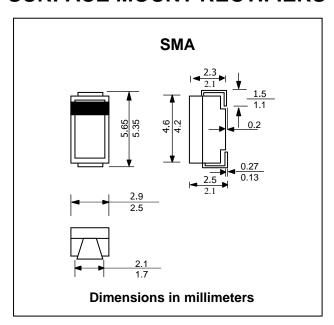
\* Case: SMA Molded plastic

\* Epoxy : UL94V-O rate flame retardant\* Polarity : Color band denotes cathode end

\* Mounting position : Any

\* Weight: 0.060 gram (Approximately)

## SURFACE MOUNT RECTIFIERS



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

RATING	SYMBOL	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNIT
Maximum Repetitive Peak Reverse Voltage	Vrrm	50 100 200 400 600 800 1000				1000	V		
Maximum RMS Voltage	VRMS	35 70 140 280 420 560 700					V		
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Current (See fig. 1)	lF	1.0							Α
Peak Forward Surge Current									
8.3ms Single half sine wave Superimposed	IFSM	30							Α
on rated load (JEDEC Method)									
Maximum Instantaneous Forward Voltage at I <sub>F</sub> = 1.0 A.	VF	1.1							٧
Maximum DC Reverse Current Ta = 25 °C	lR	1.0 5.0					.0	μА	
at rated DC Blocking Voltage Ta = 125 °C	IR(H)	50							μА
Typical Reverse Recovery Time (Note 1)	Trr	1.8							μS
Typical thermal resistance (Note 2)	$R_{\theta JA}$	75 85					5	°C/W	
	$R_{ heta JL}$	27 30					0	°C/W	
Typical Junction Capacitance at 4.0V, 1 MHz	CJ	12						pF	
Junction Temperature Range	TJ	- 55 to + 150							°C
Storage Temperature Range	Тѕтѕ	- 55 to + 150							°C

#### Notes:

- (1) Reverse Recovery Test Conditions: IF = 0.5 A, IR = 1.0 A, Irr = 0.25 A.
- (2) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas

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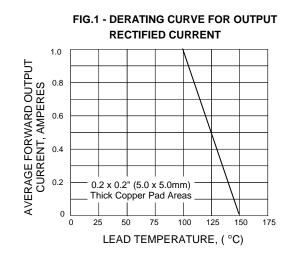


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### RATING AND CHARACTERISTIC CURVES (S1A - S1M)



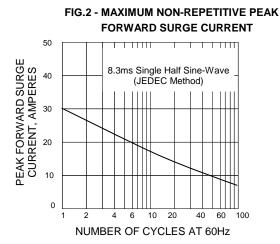
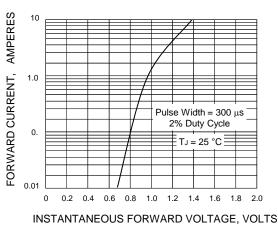


FIG.3 - TYPICAL FORWARD CHARACTERISTICS



REVERSE CURRENT, MICROAMPERES 0.0 Ta = 125 °C 0.1 Ta = 25 °C 0.0

40

60

VOLTAGE, (%)

10

0

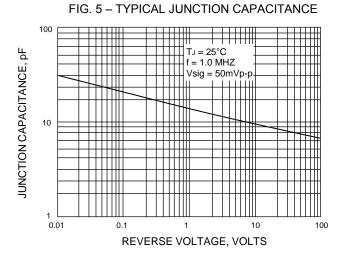
20

FIG.4 - TYPICAL REVERSE CHARACTERISTICS

120

100

PERCENT OF RATED REVERSE



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